TOSHIBA THYRISTOR SILICON PLANAR TYPE

USF05G49

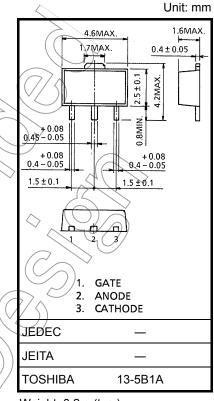
LOW POWER SWITCHING AND CONTROL APPLICATIONS

 Repetitive Peak Off-State Voltage : V_{DRM} = 400 V Repetitive Peak Reverse Voltage : V_{RRM} = 400 V
 Average On-State Current : I_T (AV) = 500 mA

MAXIMUM RATINGS

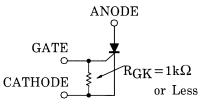
CHARACTERISTIC	SYMBOL	RATING	THAU
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	V _{DRM} V _{RRM}	400	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, $T_j = 0\sim125$ °C)	V_{RSM}	500) >>>
Average On-State Current (Half Sine Waveform)	I _{T (AV)}	500	> mA
R.M.S On-State Current	I _T (RMS)	800	mA
Peak One Cycle Surge On-State Current (Non-Repetitive)	I _{TSM}	9 (50Hz) 10 (60Hz)	A
I ² t Limit Value	I ² t	0.4	A ² s
Critical Rate of Rise of On-State Current (Note 1)	di / dt	10	A/µs
Peak Gate Power Dissipation	(R _{GM})	0.1	/w
Average Gate Power Dissipation	P _G (AV)	0.01	M
Peak Forward Gate Voltage	V _F GM	3.5	\rightarrow \vee
Peak Reverse Gate Voltage	V _{RGM} 〈	(5/))	٧
Peak Forward Gate Current	I _{GM} _	125	mA
Junction Temperature	Tj	-40~125	°C
Storage Temperature Range	T _{stg}	-40~125	°C

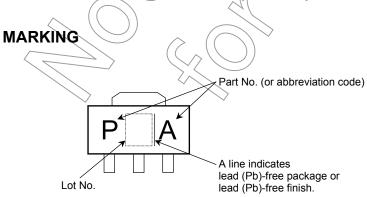
Note 1: di / dt Test condition: i_G = 5mA, t_{gw} = 10µs, t_{gr}≤250ns



Weight: 0.2 g (typ.)

Note: Should be used with gate resistance as shown below.

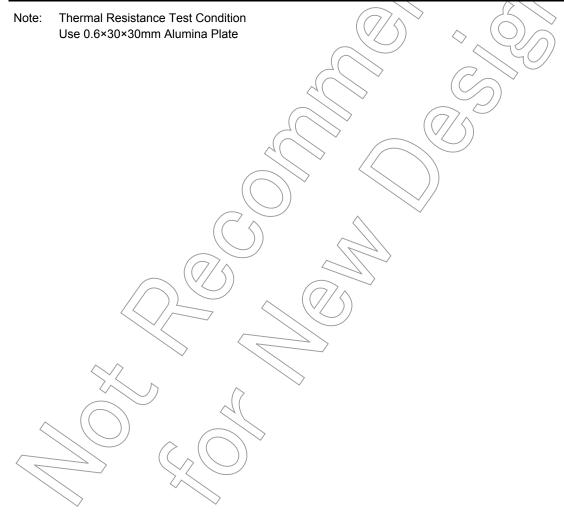




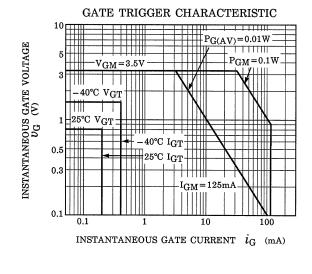
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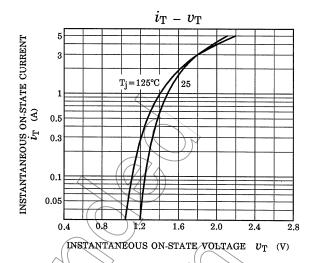
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

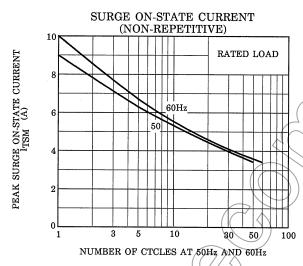
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μΑ
Peak On-State Voltage	V_{TM}	I _{TM} = 1A	/	_	1.5	٧
Gate Trigger Voltage	V _{GT}	$V_D = 6V, R_I = 100\Omega$		_	0.8	V
Gate Trigger Current	I _{GT}	$R_{GK} = 1k\Omega$	() >-	200	μΑ
Holding Current	lH	I_{TM} = 500mA, V_D = 6V R _{GK} = 1k Ω	7	_	6	mA
Critical Rate of Rise of Off-State Voltage	d _V / dt	V _{DRM} = Rated, R _{GK} = 1kΩ Exponential Rise	<u> </u>	200	_	V / µs
Gate Turn-On Time	t _{gt}	V_D = Rated, i_G = 5mA R_{GK} = 1k Ω	_	-	1.5	μs
Thermal Resistance	R _{th(j−a)}	Junction to Ambient	_	4	70	°C / W

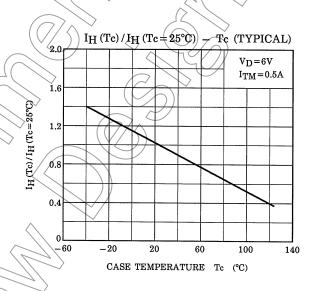


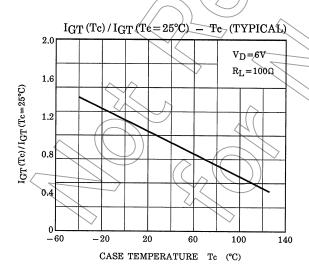
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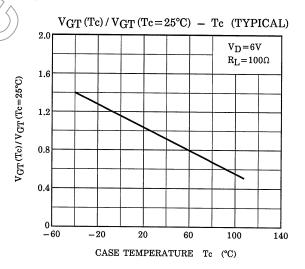


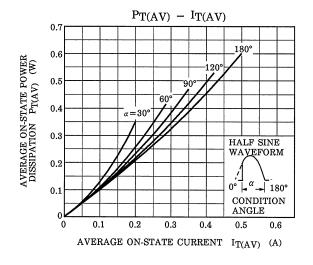


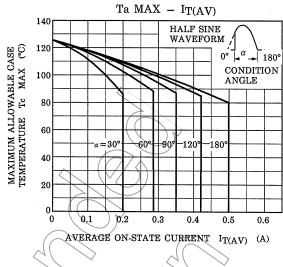


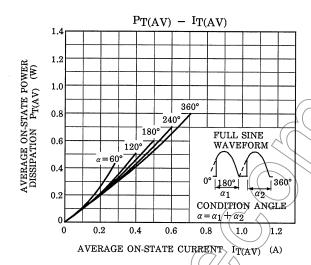


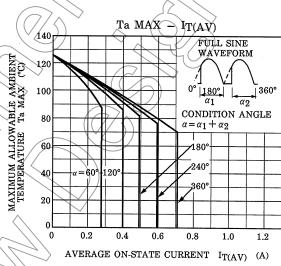


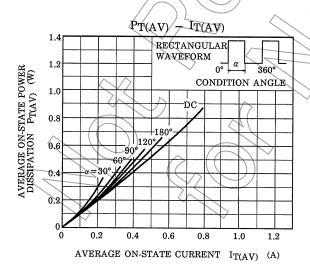


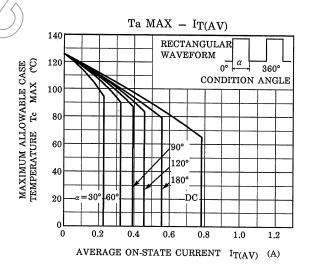


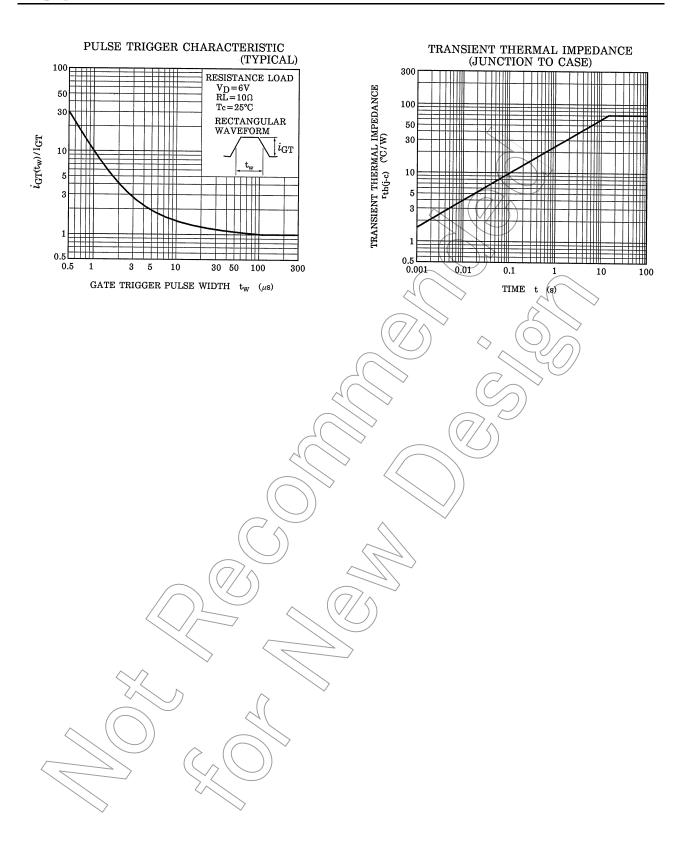














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